# 2SC2853, 2SC2854

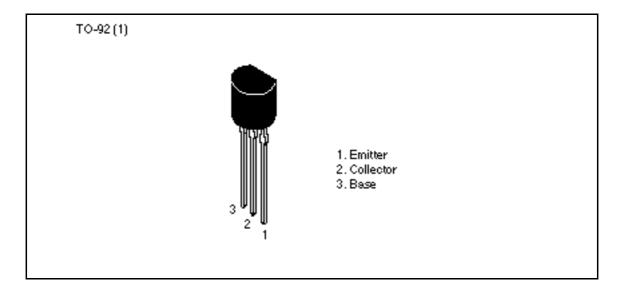
## Silicon NPN Epitaxial

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#### **Application**

- Low frequency amplifier
- Complementary pair with 2SA1188 and 2SA1189

#### Outline





### 2SC2853, 2SC2854

#### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

Item	Symbol	2SC2853	2SC2854	Unit
Collector to base voltage	$V_{CBO}$	90	120	V
Collector to emitter voltage	$V_{CEO}$	90	120	V
Emitter to base voltage	$V_{EBO}$	5	5	V
Collector current	I <sub>c</sub>	100	100	mA
Emitter current	I <sub>E</sub>	-100	-100	mA
Collector power dissipation	P <sub>c</sub>	400	400	mW
Junction temperature	Tj	150	150	°C
Storage temperature	Tstg	-55 to +150	-55 to +150	°C

#### **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

		2SC2853 2SC2854							
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	90	_	_	120	_	_	V	$I_{\rm C} = 10 \ \mu \text{A}, \ I_{\rm E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	90	_	_	120	_	_	V	$I_C = 1 \text{ mA}, R_{BE} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	_	_	5	_	_	V	$I_{E} = 10 \mu A, I_{C} = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	0.1	_	_	0.1	μΑ	$V_{CB} = 70 \text{ V}, I_{E} = 0$
Emitter cutoff current	I <sub>EBO</sub>	_	_	0.1	_	_	0.1	μΑ	$V_{EB} = 2 \text{ V}, I_{C} = 0$
DC current transfer ratio	h <sub>FE</sub> *1	250	_	800	250	_	800		$V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}^{*2}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	0.05	0.10	_	0.05	0.10	V	$I_{\rm C}$ = 10 mA, $I_{\rm B}$ = 1 mA* <sup>2</sup>
Base to emitter saturation voltage	$V_{\text{BE(sat)}}$	_	0.7	1.0	_	0.7	1.0	V	
Gain bandwidth product	f <sub>T</sub>	_	310	_	_	310	_	MHz	$V_{CE} = 6 \text{ V}, I_{C} = 10 \text{ mA}$
Collector output capacitance	Cob	_	3	_	_	3	_	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0,$ f = 1 MHz

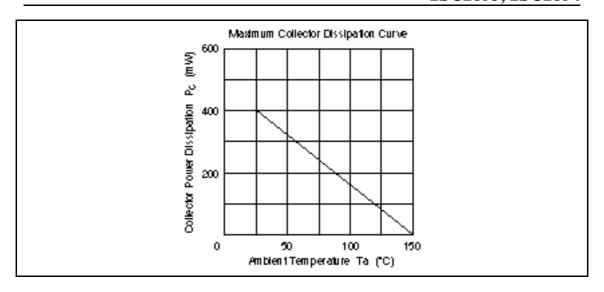
Notes: 1. The 2SC2853 and 2SC2854 are grouped by  $h_{\rm FE}$  as follows.

2. Pulse test

**D E** 250 to 500 400 to 800

See characteristic curves of 2SC2855 and 2SC2856.

### 2SC2853, 2SC2854



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